

**750kHz – 800MHz Low Phase Noise Multiplier XO**

Universal Low Phase Noise IC's

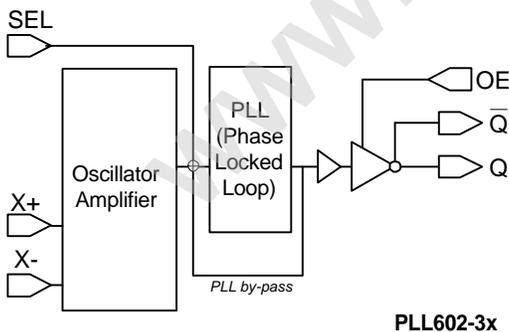
**FEATURES**

- Selectable 750kHz to 800MHz range.
- Low phase noise output (@ 10kHz frequency offset, -140dBc/Hz for 19.44MHz, -127dBc/Hz for 106.25MHz, -125dBc/Hz for 155.52MHz, -110dBc/Hz for 622.08MHz).
- CMOS (PLL602-37), PECL (PLL602-35 and PLL602-38) or LVDS (PLL602-39) output.
- 12 to 25MHz crystal input.
- No external load capacitor or varicap required.
- Output Enable selector.
- Selectable 1/16 to 32x frequency multiplier.
- 3.3V operation.
- Available in 16-Pin (TSSOP or 3x3mm QFN).

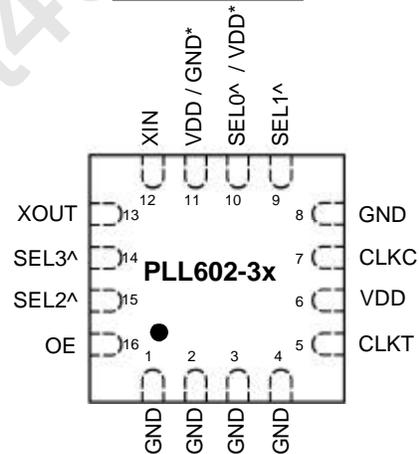
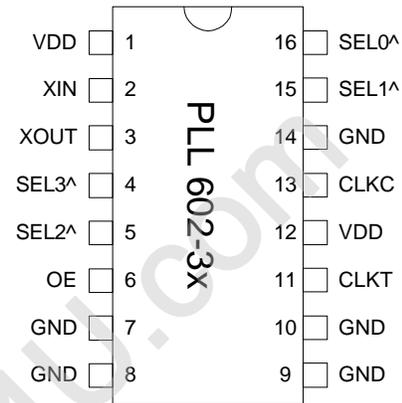
**DESCRIPTIONS**

The PLL602-35 (PECL with inverted OE), PLL602-37 (CMOS), PLL602-38 (PECL), and PLL602-39 (LVDS) are high performance and low phase noise XO IC chips. They provide phase noise performance as low as -125dBc at 1kHz offset (at 155MHz), by multiplying the input crystal frequency up to 32x. They accept fundamental parallel resonant mode crystals from 12 to 25MHz.

**BLOCK DIAGRAM**



**PIN CONFIGURATION (Top View)**



^: Internal pull-up  
 \*: On 3x3 package, PLL602-35/-38 do not have SEL0 available: Pin 10 is VDD, pin 11 is GND. However, PLL602-37/-39 have SEL0 (pin 10), and pin 11 is VDD. See pin assignment table for details.

**OUTPUT ENABLE LOGICAL LEVELS**

Part #	OE	State
PLL602-38	0 (Default)	Output enabled
	1	Tri-state
PLL602-35 PLL602-37 PLL602-39	0	Tri-state
	1 (Default)	Output enabled

OE Input: Logical states defined by PECL levels for PLL602-38  
 Logical states defined by CMOS levels for PLL602-35/-37/-39

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**FREQUENCY SELECTION TABLE**

SEL3	SEL2	SEL1	SEL0	Selected Multiplier
0	0	1	1	Fin x 32
0	1	1	0	Fin / 8
0	1	1	1	Fin x 2
1	0	0	1	Fin / 2
1	0	1	0	Fin / 16
1	0	1	1	Fin x 4
1	1	0	0	Fin / 4
1	1	0	1	Fin x 8
1	1	1	0	Fin x 16
1	1	1	1	No multiplication

Note: SEL0 is not available (always "1") for PLL602-35 and PLL602-38 in 3x3mm package

**PIN DESCRIPTIONS PLL602-35 and PLL602-38 (see next page of PLL602-37/-39)**

Name	TSSOP Pin number	3x3mm QFN Pin number	Type	Description
XIN	2	12	I	Crystal in connector.
XOUT	3	13	I	Crystal out connector.
OE	6	16	I	Output enable pin (see OE logic state table on page 1).
GND	7,8,9,10,14	1,2,3,4,8,11	P	GND.
CLKT	11	5	O	True output PECL
CLKC	13	7	O	Complementary output PECL.
SEL0	16	Not available	I	Multiplier selector pins. These pins have an internal pull-up that will default SEL to '1' when not connected to GND.
SEL1	15	9	I	
SEL2	5	15	I	
SEL3	4	14	I	
VDD	1, 12	6,10	P	+3.3V VDD.

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**PIN DESCRIPTIONS PLL602-37/-39 (see previous page of PLL602-35/-38)**

Name	TSSOP Pin number	3x3mm QFN Pin number	Type	Description
XIN	2	12	I	Crystal in connector.
XOUT	3	13	I	Crystal out connector.
OE	6	16	I	Output enable pin (see OE logic state table on page 1).
GND	7,8,9,10,14	1,2,3,4,8	P	GND.
CLKT	11	5	O	True output LVDS (PLL602-39) (N/C for PLL602-37)
CLKC	13	7	O	Complementary output LVDS (PLL602-39) (CMOS out for PLL602-37).
SEL0	16	10	I	Multiplier selector pins. These pins have an internal pull-up that will default SEL to '1' when not connected to GND.
SEL1	15	9	I	
SEL2	5	15	I	
SEL3	4	14	I	
VDD	1, 12	6,11	P	+3.3V VDD.

**ELECTRICAL SPECIFICATIONS**
**1. Absolute Maximum Ratings**

PARAMETERS	SYMBOL	MIN.	MAX.	UNITS
Supply Voltage	$V_{DD}$		7	V
Input Voltage, dc	$V_I$	$V_{SS}-0.5$	$V_{DD}+0.5$	V
Output Voltage, dc	$V_O$	$V_{SS}-0.5$	$V_{DD}+0.5$	V
Storage Temperature	$T_S$	-65	150	°C
Ambient Operating Temperature*	$T_A$	-40	85	°C
Junction Temperature	$T_J$		125	°C
Lead Temperature (soldering, 10s)			260	°C
Input Static Discharge Voltage Protection			2	kV

Exposure of the device under conditions beyond the limits specified by Maximum Ratings for extended periods may cause permanent damage to the device and affect product reliability. These conditions represent a stress rating only, and functional operations of the device at these or any other conditions above the operational limits noted in this specification is not implied.

\* **Note:** Operating Temperature is guaranteed by design for all parts (COMMERCIAL and INDUSTRIAL), but tested for INDUSTRIAL grade only.

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**2. Crystal Specifications**

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Crystal Resonator Frequency	$F_{XIN}$	Parallel Fundamental Mode	12		25	MHz
Crystal Loading Rating	$C_L$ (xtal)			12		pF
Recommended ESR	$R_E$	AT cut			30	$\Omega$

**3. General Electrical Specifications**

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Supply Current, Dynamic (with Loaded Outputs)	$I_{DD}$	PECL/LVDS/CMOS	$F_{out} < 24\text{MHz}$			25/25/15	mA
			$24\text{MHz} < F_{out} < 96\text{MHz}$			65/45/30	
			$96\text{MHz} < F_{out} < 800\text{MHz}$			100/80/40	
Operating Voltage	$V_{DD}$		3.13		3.47	V	
Output Clock Duty Cycle		@ 1.4V (CMOS) @ 1.25V (LVDS) @ $V_{DD} - 1.3\text{V}$ (PECL)	45 45 45	50 50 50	55 55 55	%	
Short Circuit Current				$\pm 50$		mA	

**4. AC Electrical Specifications**

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Input Crystal Frequency			12		25	MHz
Output Clock Rise Time		0.8V ~ 2.0V with 10 pF load			1.5	ns
		0.3V ~ 3.0V with 15 pF load		3.7	5	
Output Clock Fall Time		2.0V ~ 0.8V with 10 pF load			1.5	
		3.0V ~ 0.3V with 15pF load		3.7	5	
Output Clock Duty Cycle		Measured @ 1.4V	45	50	55	%
Short Circuit Current				$\pm 50$		mA

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**5. Jitter specifications**

PARAMETERS	CONDITIONS	FREQUENCY	MIN.	TYP.	MAX.	UNITS
Period jitter RMS	With capacitive decoupling between VDD and GND.	19.44MHz		5		ps
		77.76MHz		8		
		155.52MHz		9		
		622.08MHz		10		
Accumulated jitter RMS	With capacitive decoupling between VDD and GND. Over 10,000 cycles.	155.52MHz		TBM		ps
Integrated jitter RMS	Integrated 12 kHz to 20 MHz	155.52MHz		3	4	ps

**6. Phase noise specifications**

PARAMETERS	FREQUENCY	@10Hz	@100Hz	@1kHz	@10kHz	@100kHz	UNITS
Phase Noise relative to carrier	19.44MHz	-60	-90	-112	-140	-150	dBc/Hz
	106.25MHz	-60	-90	-112	-127	-125	
	155.52MHz	-60	-90	-112	-125	-123	
	622.08MHz	-60	-90	-109	-110	-109	

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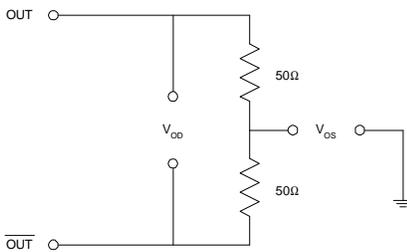
**7. LVDS Electrical Characteristics**

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Output Differential Voltage	$V_{OD}$	$R_L = 100 \Omega$ (see figure)	247	355	454	mV
$V_{DD}$ Magnitude Change	$\Delta V_{OD}$		-50		50	mV
Output High Voltage	$V_{OH}$			1.4	1.6	V
Output Low Voltage	$V_{OL}$		0.9	1.1		V
Offset Voltage	$V_{OS}$		1.125	1.2	1.375	V
Offset Magnitude Change	$\Delta V_{OS}$		0	3	25	mV
Power-off Leakage	$I_{OXD}$	$V_{out} = V_{DD}$ or GND $V_{DD} = 0V$		$\pm 1$	$\pm 10$	$\mu A$
Output Short Circuit Current	$I_{OSD}$			-5.7	-8	mA

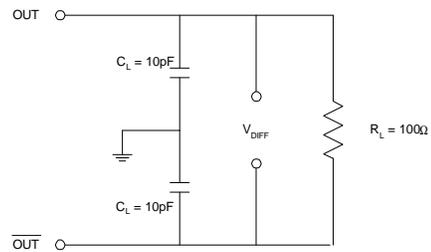
**8. LVDS Switching Characteristics**

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Differential Clock Rise Time	$t_r$	$R_L = 100 \Omega$ $C_L = 10 \text{ pF}$ (see figure)	0.2	0.7	1.0	ns
Differential Clock Fall Time	$t_f$		0.2	0.7	1.0	ns

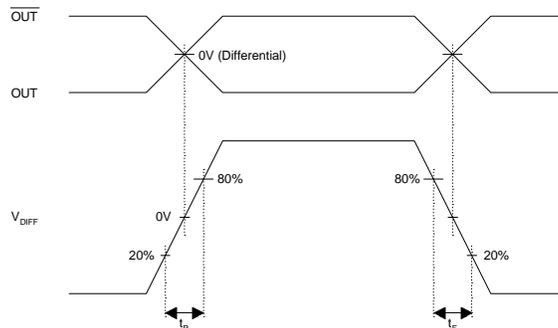
LVDS Levels Test Circuit



LVDS Switching Test Circuit



LVDS Transition Time Waveform



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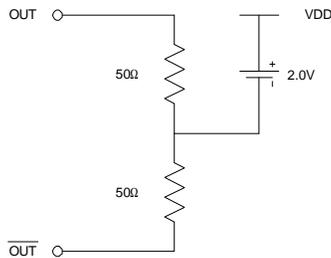
**9. PECL Electrical Characteristics**

PARAMETERS	SYMBOL	CONDITIONS	MIN.	MAX.	UNITS
Output High Voltage	$V_{OH}$	$R_L = 50 \Omega$ to $(V_{DD} - 2V)$ (see figure)	$V_{DD} - 1.025$		V
Output Low Voltage	$V_{OL}$			$V_{DD} - 1.620$	V

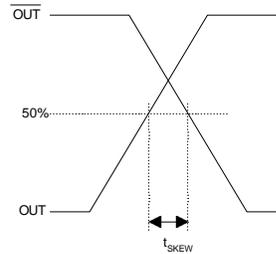
**10. PECL Switching Characteristics**

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Clock Rise Time	$t_r$	0.8V ~ 2.0V			1.5	ns
Clock Fall Time	$t_f$	2.0V ~ 0.8V			1.5	ns
Duty Cycle		Measured @ 1.4V	40	50	60	%

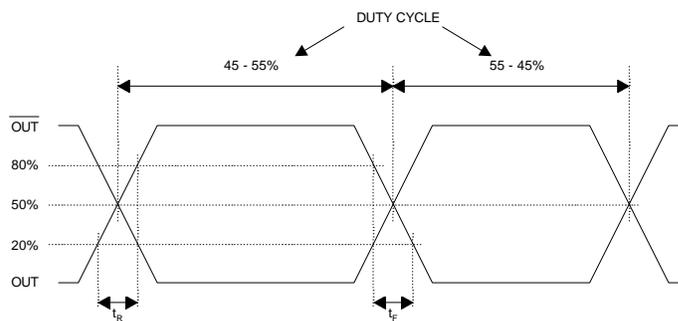
PECL Levels Test Circuit



PECL Output Skew



PECL Transition Time Waveform



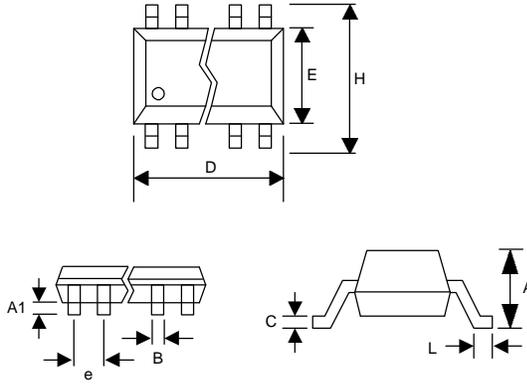
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**PACKAGE INFORMATION**

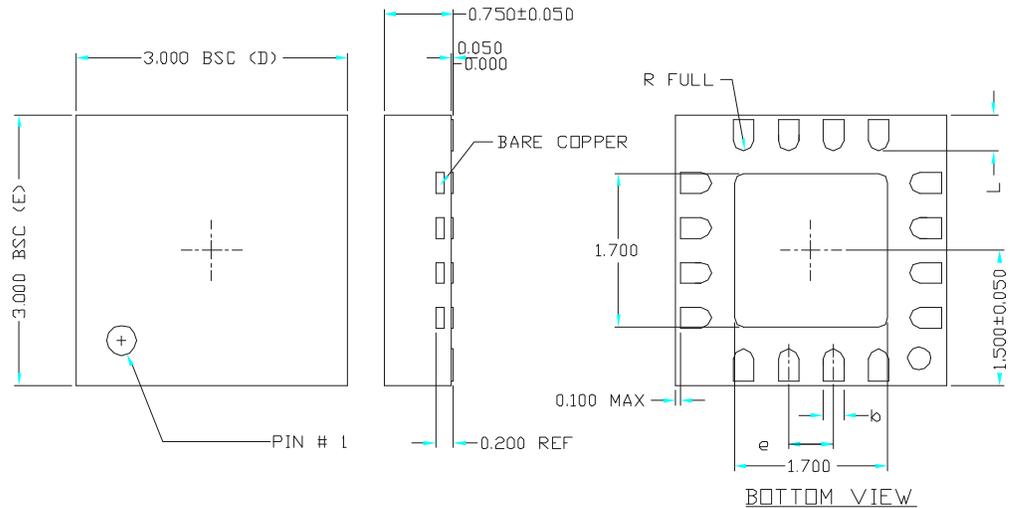
16 PIN Narrow SOIC, TSSOP ( mm )

Symbol	SOIC		TSSOP	
	Min.	Max.	Min.	Max.
A	1.35	1.75	-	1.20
A1	0.10	0.25	0.05	0.15
B	0.33	0.51	0.19	0.30
C	0.19	0.25	0.09	0.20
D	9.80	10.00	4.90	5.10
E	3.80	4.00	4.30	4.50
H	5.80	6.20	6.40 BSC	
L	0.40	1.27	0.45	0.75
e	1.27 BSC		0.65 BSC	



VARIATIONS:

SYMBOL	16 LD		
	MIN	NDM	MAX
e	0.50 BSC		
k	0.18	0.23	0.30
L	0.30	0.40	0.50
ND	4		
NE	4		



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**ORDERING INFORMATION**

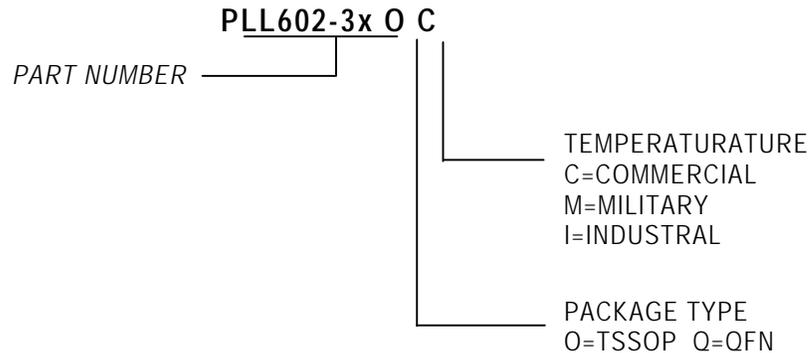
*For part ordering, please contact our Sales Department:*

47745 Fremont Blvd., Fremont, CA 94538, USA

Tel: (510) 492-0990 Fax: (510) 492-0991

**PART NUMBER**

The order number for this device is a combination of the following:  
Device number, Package type and Operating temperature range



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